







A wire has a non-uniform cross-sectional area as shown in figure. A steady current *i* flows through it. Which one of the following statement is correct





The drift speed of electron is constant on moving from *A* to *B* The drift speed increases

(c) The drift speed decreases on moving from *A* to *B* (d) The drift speed varies randomly

Example: 3 Two wires A and B of the same material, having radii in the ratio 1:2 and carry currents in the ratio 4 : 1. The ratio of drift speeds of electrons in A and B is

$$\int_{a}^{b} = \int_{a}^{b} \int_$$





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Example: 12

le: 12 The equivalent resistance between points *A* and *B* of an infinite network of resistance, each of 1 Ω , connected as shown is



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Example: 13 The equivalent resistance between A and B in the circuit shown will be





?

Example: 14 A current of 2 A flows in a system of conductors as shown. The potential difference $(V_A - V_B)$ will be $V_A - V_B = V_B$



A

VAB = E - ir

$$\ddot{i} = \frac{2}{4} = 0.5 A$$

 $V_{AB} = 2 - 0.5 \times 0.1 = 1.95V$

B

IIT-JEE/NEET-PHYSICS AFALT ELECTROSTATICS Example: 17 A group of N cells whose emf varies directly with the internal resistance as per the equation $E_N = 1.5 r_N$ are connected as shown in the following figure. The current *i* in the circuit is (a) 0.51 amp (b) 5.1 amp (c) 0.15 amp (d) 1.5 amp ENet = NE Yeg = No i= $\frac{1.57+1.58+1.58}{8+1.58} = \frac{1.57+1.58+1.58}{8+1.58} = \frac{1.57+1.58}{8+1.58} = \frac{1.57+1.58}{8} = \frac{1$ 0 | $= E_{1} + E_{2} + E_{3} +$ $\gamma_{1} + \gamma_{2} + \gamma_{3} +$ = 1.5 X NY = 1.5 Aup. **Example: 18** In a mixed grouping of identical cells 5 rows are connected in parallel by each row contains 10 cell. This combination send a current i through an external resistance of 20 Ω . If the emf and internal resistance of each cell is 1.5 *volt* and 1 Ω respectively (b) 0.25 (c) $\frac{10E}{20+2\%} = \frac{10\times1.5}{20+2}$ then the value of *i* is [KCET 2000] (d) (a) 0.14 20. 0.68 10 cells $1 = \frac{15}{2}$ A IOE 108 - 10 cells -----ΙΟΥ Example: 19 In the adjoining circuit, the battery E_1 has as emf of 12 volt and zero internal resistance, while the battery *E* has an emf of 2 *volt*. If the galvanometer reads zero, 502 then the value of resistance X ohm is [N 500Ω rows. (a) 10 (b) 100 N . E E_1 (c) 500 (d) 200

OE

01-



 $V = IR = \frac{1}{50} \times K$ $\frac{1}{2} = \frac{1}{50}$

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[CPMT 1986,

A 2A 2V B 2A $E_3 = 2V$ B 4OExample: 21 The magnitude and direction of the current in the circuit shown will be (a) $\frac{7}{3}A$ from a to b through e (b) $\frac{7}{3}A$ from b and a through e (c) 1.0 A from b to a through e (d) 1.0 A from a to b through e Hint H

6N

Example: 22 Figure represents a part of the closed circuit. The potential difference between points A and $B(V_A - V_B)$ is

(a) + 9 V(b) - 9 V(c) + 3 V(d) + 6 V



4V

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Example: 24 In the circuit shown in figure, find the current through the branch *BD*





Example: 25 A part of a circuit in steady state along with the current flowing in the branches, with value of each resistance is shown in figure. What will be the energy stored in the capacitor C_0 [IIT-JEE 1986] Cap. is fully thanked.



Example: 26 In the following circuit the potential difference between *P* and *Q* is



$$V = IR$$

$$5 = 2R$$

$$R = 2 \cdot 5^{2} M$$



- (a) Zero
 - (b) 0.5 volt
 - (c) 1 *volt*
 - (d) 2 *volt*



Ideal Ammeter has zero presistance. that is why it will Jaaw Ovolts.



0.06A (a) (a) (c) (0.06 - b) (c)(a) (c)

 $\begin{array}{c} 0.06 \ A \text{ when a shunt of resistance } r \text{ connected across it. What is the maximum} \\ \hline \\ (a) 0.01 \ A \\ (b) 0.02 \ A \\ (c) 0.03 \ A \\ (c) 0.03 \ A \\ (d) 0.04 \$

(0.03 - ig)

 $\frac{9}{31}$. The potential difference between points *A* and *B* of adjoining figure is





48



-V_R

32. Resistances of 6 *ohm* each are connected in the manner shown in adjoining figure. With the current 0.5 *ampere* as shown in figure, the potential difference $V_P - V_Q$ is

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34. In the given figure, when key *k* is opened, the reading of the ammeter *A* will be



$$V = 0.8 \times 3 = 2.4 \gamma$$

35. If the current through 3 Ω resistor is 0.8 *A* then the potential drop through 4 Ω resistor is

[AFMC 10

(a) 9.6V
(b) 4.8V
(c) 2.6V
(d) 2.2V
hint in parallel
potential is same.



[MP PMT 1



Vp-VQ=? Potential difference between the points P and Q in the electric circuit shown is 36.

[KCET (Engg./Med.) 19







- **37.** The value of *i* in the following circuit diagram will be
 - (a) $\frac{3}{2}A$ (b) $\frac{3}{4}A$ (c) $\frac{1}{2}A$

38.





In the following circuit the value of currents i_A and i_B are



400



- **39.** The emf of the battery shown in figure is
 - (a) 12 V
 - (b) 16 V
 - (c) 18 V
 - (d) 15 V



40. Consider four circuits shown in the figure below. In which circuit power dissipated s greatest ? (Neglect the internal resistance of the power supply)



- **41.** In the steady state what will be the power dissipation in following circuit
 - (a) 1.5 W
 - (b) 2 W
 - (c) 1 W
 - (d) None of these

